TOSHIBA THYRISTOR SILICON PLANAR TYPE

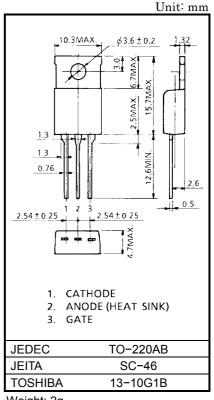
# SF10G41A,SF10J41A

### MEDIUM POWER CONTROL APPLICATIONS

 Repetitive Peak Off-State Voltage : VDRM = 400,600V Repetitive Peak Reverse Voltage : VRRM = 400,600V
 Average On-State Current : IT (AV) = 10A
 Gate Trigger Current : IGT = 15mA (Max.)

### **MAXIMUM RATINGS**

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SF10G41A	$V_{DRM}$	400	V	
	SF10J41A	$V_{RRM}$	600		
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, T <sub>j</sub> = 0~125°C)	SF10G41A	$V_{RSM}$	500	V	
	SF10J41A		720	V	
Average On-State Current (Half Sine Waveform Tc = 79°C)		I <sub>T (AV)</sub>	10	Α	
R.M.S On-State Current		I <sub>T (RMS)</sub>	16	Α	
Peak One Cycle Surge On-State Current (Non-Repetitive)		I <sub>TSM</sub>	160 (50Hz)	А	
			176 (60Hz)		
I <sup>2</sup> t Limit Value		ı²t	125	A <sup>2</sup> s	
Critical Rate of Rise of On-State Curret		di / dt	100	A / μs	
Peak Gate Power Dissipation		$P_{GM}$	5	W	
Average Gate Power Dissipation		P <sub>G (AV)</sub>	0.5	W	
Peak Forward Gate Voltage		$V_{FGM}$	10	<b>V</b>	
Peak Reverse Gate Voltage		$V_{RGM}$	-5	٧	
Peak Forward Gate Current		I <sub>GM</sub>	2	Α	
Junction Temperature		Tj	-40~125	°C	
Storage Temperature Ra	ange	T <sub>stg</sub>	-40~125	°C	



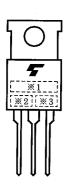
Weight: 2g



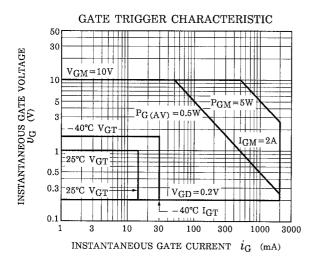
## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

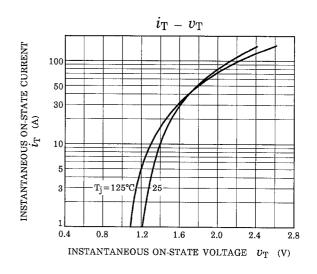
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub> = Rated		10	μΑ
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 30A	_	1.6	V
Gate Trigger Voltage	$V_{GT}$	$V_D = 6V, R_L = 10\Omega$		1.0	V
Gate Trigger Current	I <sub>GT</sub>			15	mA
Gate Non-Trigger Voltage	$V_{GD}$	V <sub>D</sub> = Rated × 2 / 3, Tc = 125°C	0.2	_	V
Critical Rate of Rise of Off-State Voltage	dv / dt	V <sub>DRM</sub> = Rated × 2 / 3, Tc = 125°C Exponential Rise		_	V / µs
Holding Current	lΗ	V <sub>D</sub> = 6V, I <sub>TM</sub> = 1A	_	40	mA
Latching Current	ΙL	$V_D = 6V, f = 50Hz, t_{gw} = 50\mu S, i_G = 30mA$	_	60	mA
Thermal Resistance	R <sub>th (j-c)</sub>	Junction to Case	_	2.0	°C/W

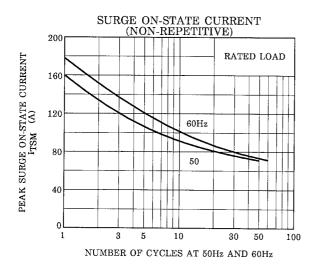
### **MARKING**

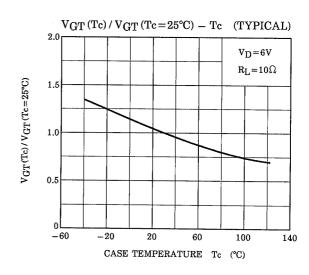


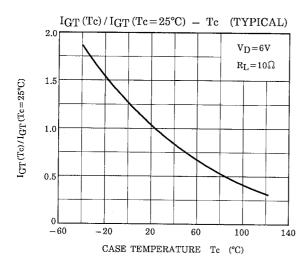
NUMBER	SYMBOL		MARK
*1		SF10G41A	SF10G41
	TYPE	SF10J41A	SF10J41
*2		SF10G41A, SF10J41A	A
*3		h (Starting from Alphabet A)  (Last Decimal Digit of the Current Year)	Example 8A : January 1998 8B : February 1998 8L : December 1998

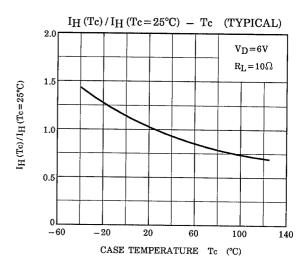


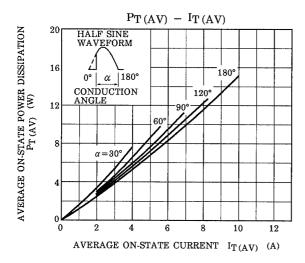


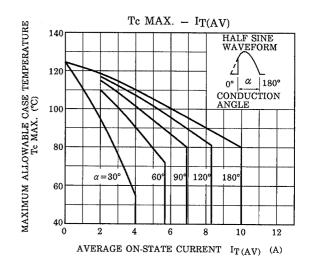


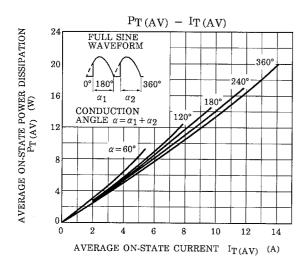


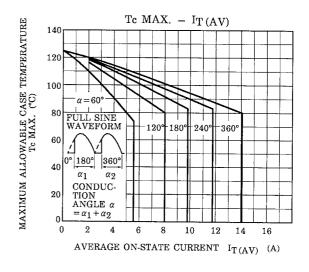


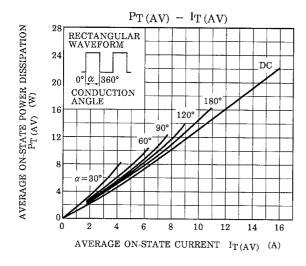


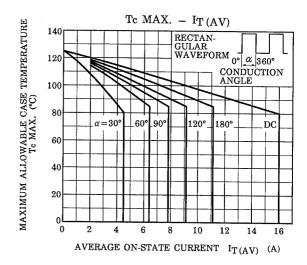


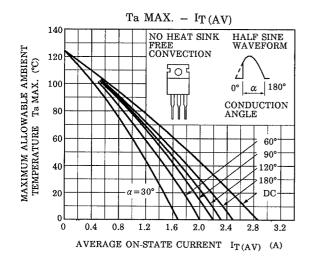


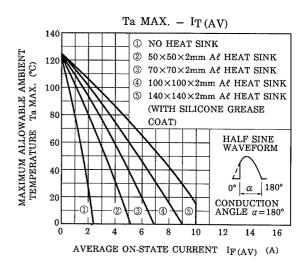


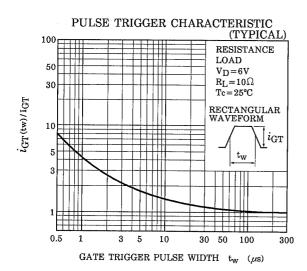


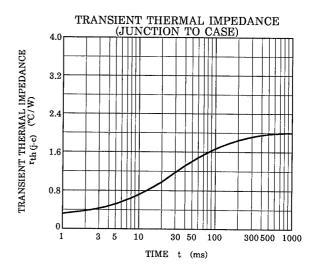












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